



# 2N7002KTB

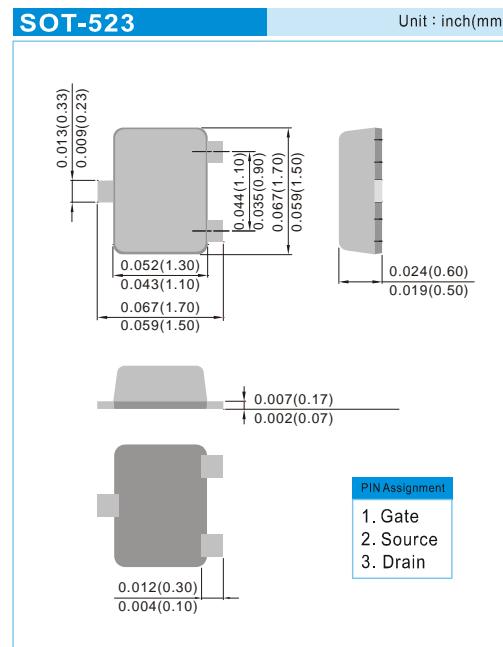
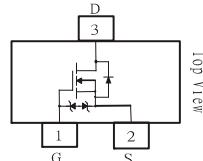
## 60V N-Channel Enhancement Mode MOSFET - ESD Protected

### FEATURES

- $R_{DS(ON)}$ ,  $V_{GS} @ 10V, I_{DS} @ 500mA = 3\Omega$
- $R_{DS(ON)}$ ,  $V_{GS} @ 4.5V, I_{DS} @ 200mA = 4\Omega$
- Advanced Trench Process Technology
- High Density Cell Design For Ultra Low On-Resistance
- Very Low Leakage Current In Off Condition
- Specially Designed for Battery Operated Systems, Solid-State Relays  
Drivers : Relays, Displays, Lamps, Solenoids, Memories, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS2.0  
(2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std. . (Halogen Free)

### MECHANICAL DATA

- Case: SOT-523 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00007 ounces, 0.002 grams
- Marking: 27



### Maximum RATINGS and Thermal Characteristics ( $T_A=25^\circ C$ unless otherwise noted )

PARAMETER	Symbol	Limit	Units
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	115	mA
Pulsed Drain Current <sup>1)</sup>	$I_{DM}$	800	mA
Maximum Power Dissipation $T_A=25^\circ C$ $T_A=75^\circ C$	$P_D$	200 150	mW
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to + 150	°C
Junction-to Ambient Thermal Resistance(PCB mounted) <sup>2</sup>	$R_{\theta JA}$	883	°C/W

Note:1.Maximum DC current limited by the package

2.Surface mounted on FR4 board,  $t \leq 10$  sec

3.Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$

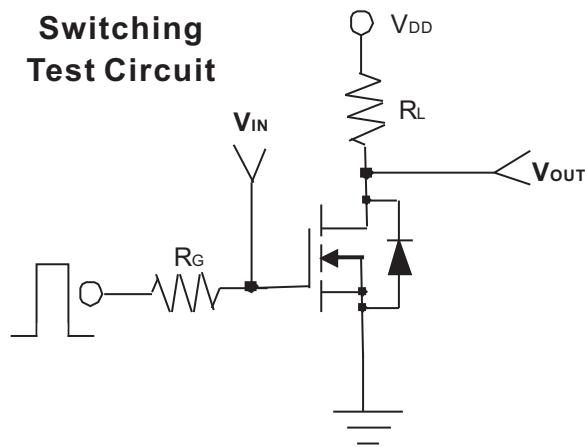


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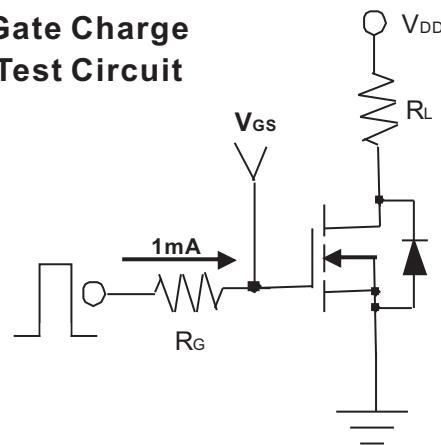
## ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Units
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=10\mu A$	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	-	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=200mA$	-	-	4.0	$\Omega$
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=500mA$	-	-	3.0	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60V, V_{GS}=0V$	-	-	1	$\mu A$
Gate Body Leakage	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 10$	$\mu A$
Forward Transconductance	$g_{fs}$	$V_{DS}=15V, I_D=250mA$	100	-	-	mS
Dynamic						
Total Gate Charge	$Q_g$	$V_{DS}=15V, I_D=200mA$ $V_{GS}=4.5V$	-	-	0.8	nC
Turn-On Delay Time	$td_{(on)}$	$V_{DD}=30V, R_L=150\Omega$ $I_D=200mA, V_{GEN}=10V$ $R_G=10\Omega$	-	-	20	ns
Turn-Off Delay Time	$td_{(off)}$		-	-	125	
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V$ $f=1.0MHz$	-	-	35	pF
Output Capacitance	$C_{oss}$		-	-	10	
Reverse Transfer Capacitance	$C_{rss}$		-	-	5	
Source-Drain Diode						
Diode Forward Voltage	$V_{SD}$	$I_s=200mA, V_{GS}=0V$	-	0.82	1.3	V
Continuous Diode Forward Current	$I_s$	-	-	-	115	mA
Pulsed Diode Forward Current	$I_{sM}$	-	-	-	800	mA

Switching  
Test Circuit



Gate Charge  
Test Circuit





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Typical Characteristics Curves ( $T_A=25^\circ\text{C}$ ,unless otherwise noted)

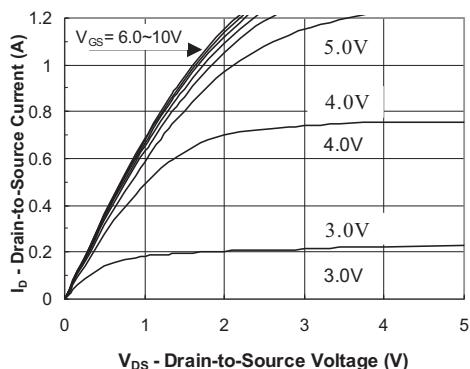


FIG.1- Output Characteristic

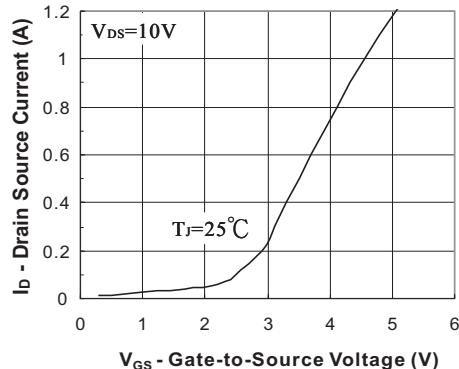


FIG.2- Transfer Characteristic

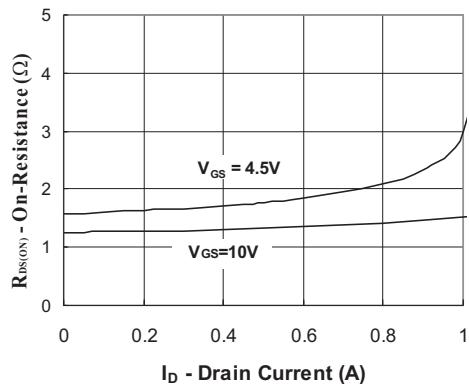


FIG.3- On Resistance vs Drain Current

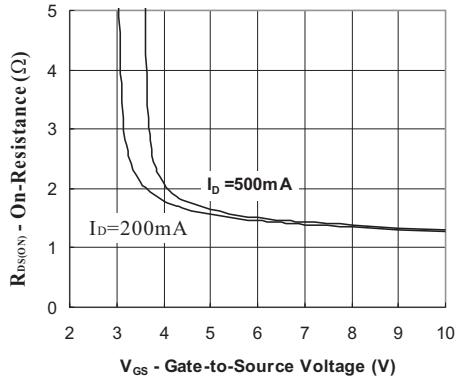


FIG.4- On Resistance vs Gate to Source Voltage

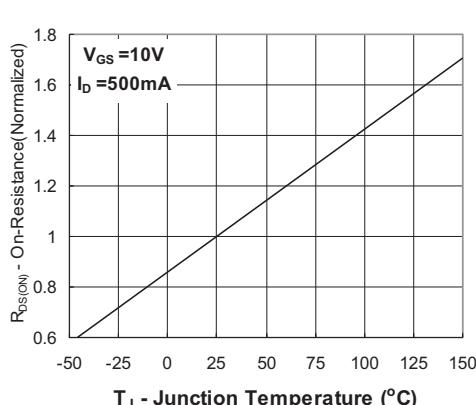
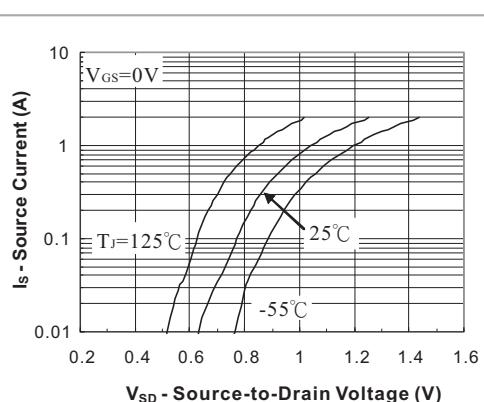
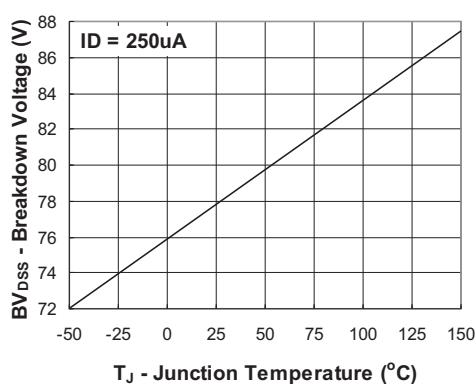
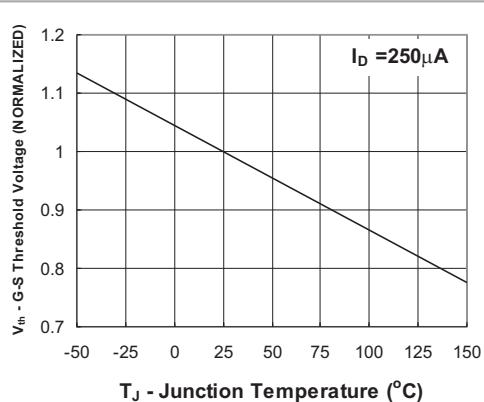
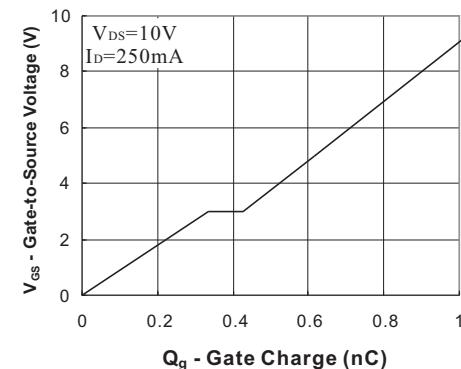
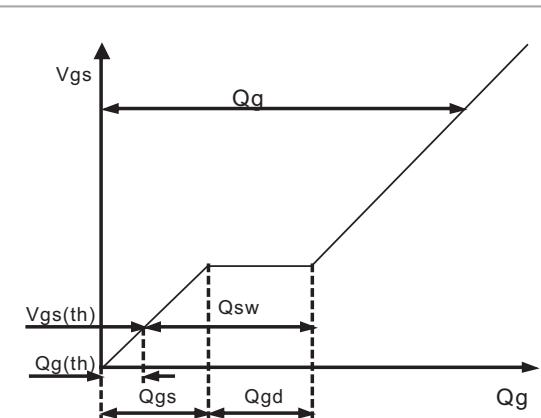


FIG.5- On Resistance vs Junction Temperature



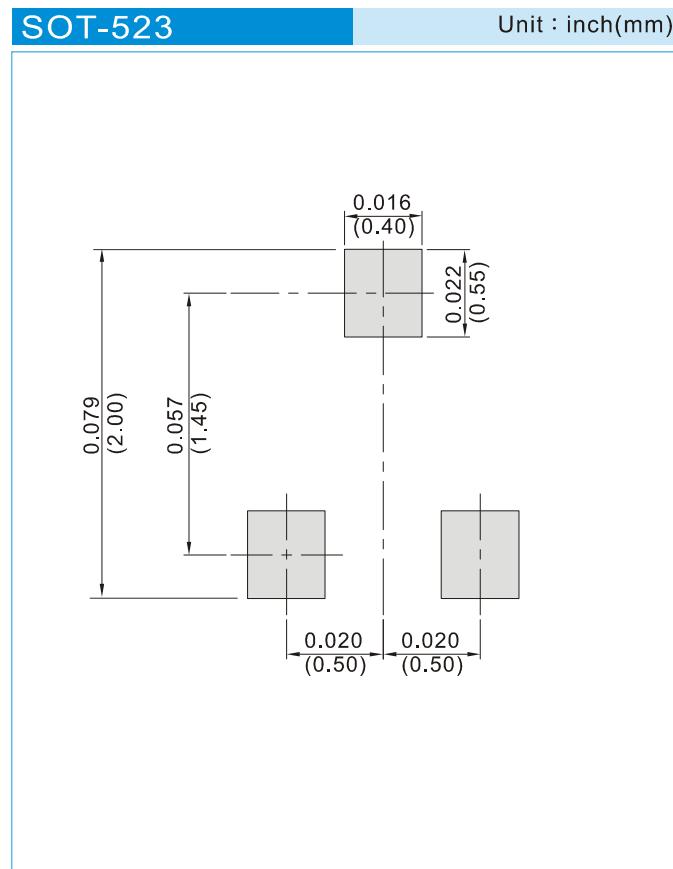
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## MOUNTING PAD LAYOUT



## ORDER INFORMATION

- Packing information  
T/R - 4K per 7" plastic Reel



# 2N7002KTB

## Part No\_packing code\_Version

2N7002KTB\_R1\_00001

For example :

RB500V-40\_R2\_00001

- Part No.
- Serial number
- Version code means HF
- Packing size code means 13"
- Packing type means T/R

Packing Code XX				Version Code XXXXX		
Packing type	1 <sup>st</sup> Code	Packing size code	2 <sup>nd</sup> Code	HF or RoHS	1 <sup>st</sup> Code	2 <sup>nd</sup> ~5 <sup>th</sup> Code
Tape and Ammunition Box (T/B)	A	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	B	13"	2			
Tube Packing (T/P)	T	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			



## **2N7002KTB**

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